

/ Descriptions

WR0459I ММ Ё SQS æ Ñ ç s ll 1 Silicon PNP transistor in a TO-126F Plastic Package.

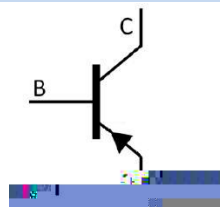
/ Features

лъ 5VG99<+D, Ы ´
Complementary pair with 2SD669(A).

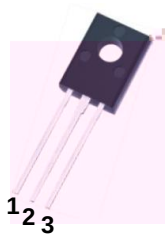
/ Applications

æ ã ã H l i ' ð z
Low frequency power amplifier.

/ Equivalent Circuit



/ Pinning

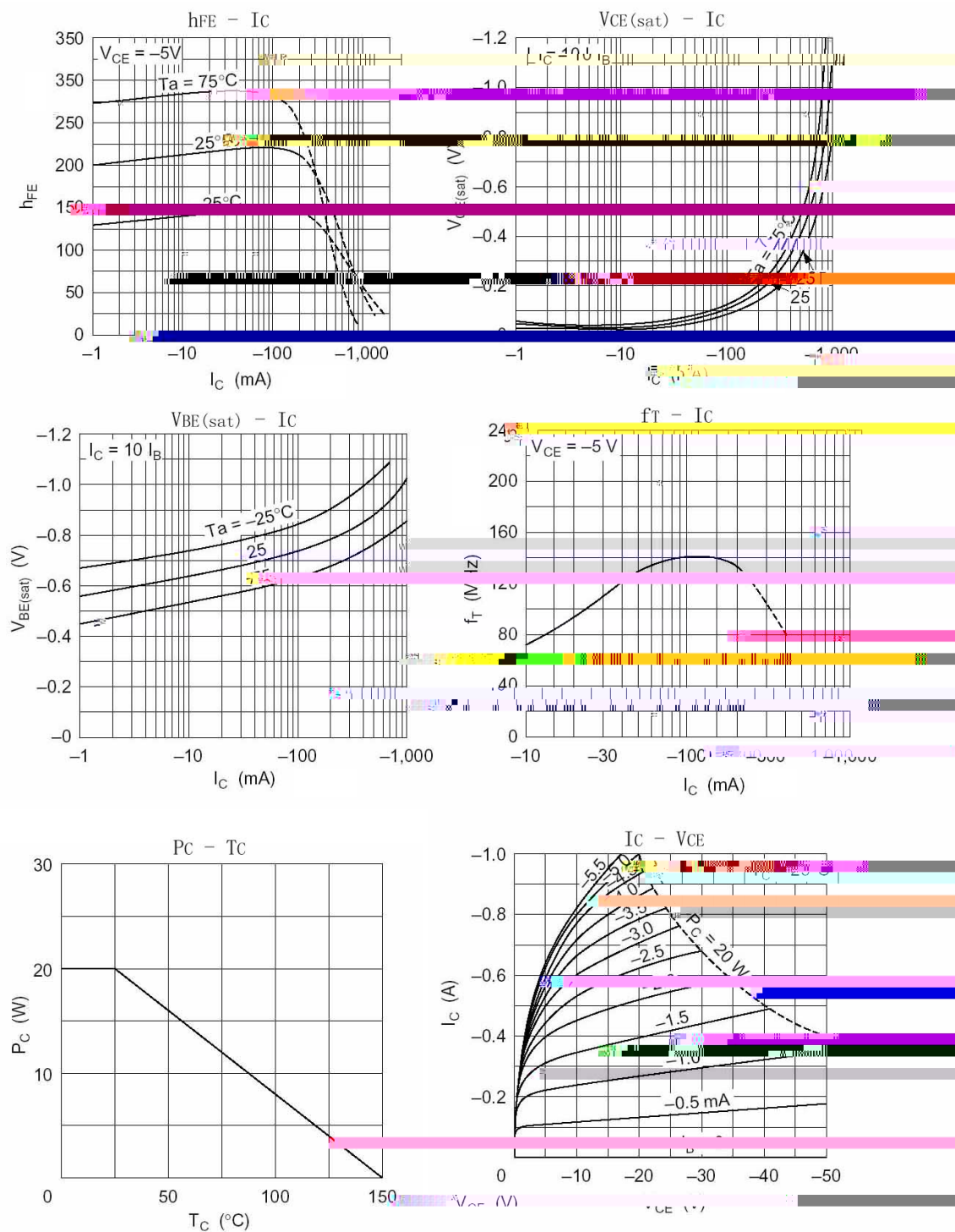


PIN1 χ Emitter PIN 2 χ Collector PIN 3 χ Base

/ h_{FE} Classifications & Marking

h _{FE} Classifications Symbol	B	C	D
h _{FE} Range	60 120	100 200	160 320

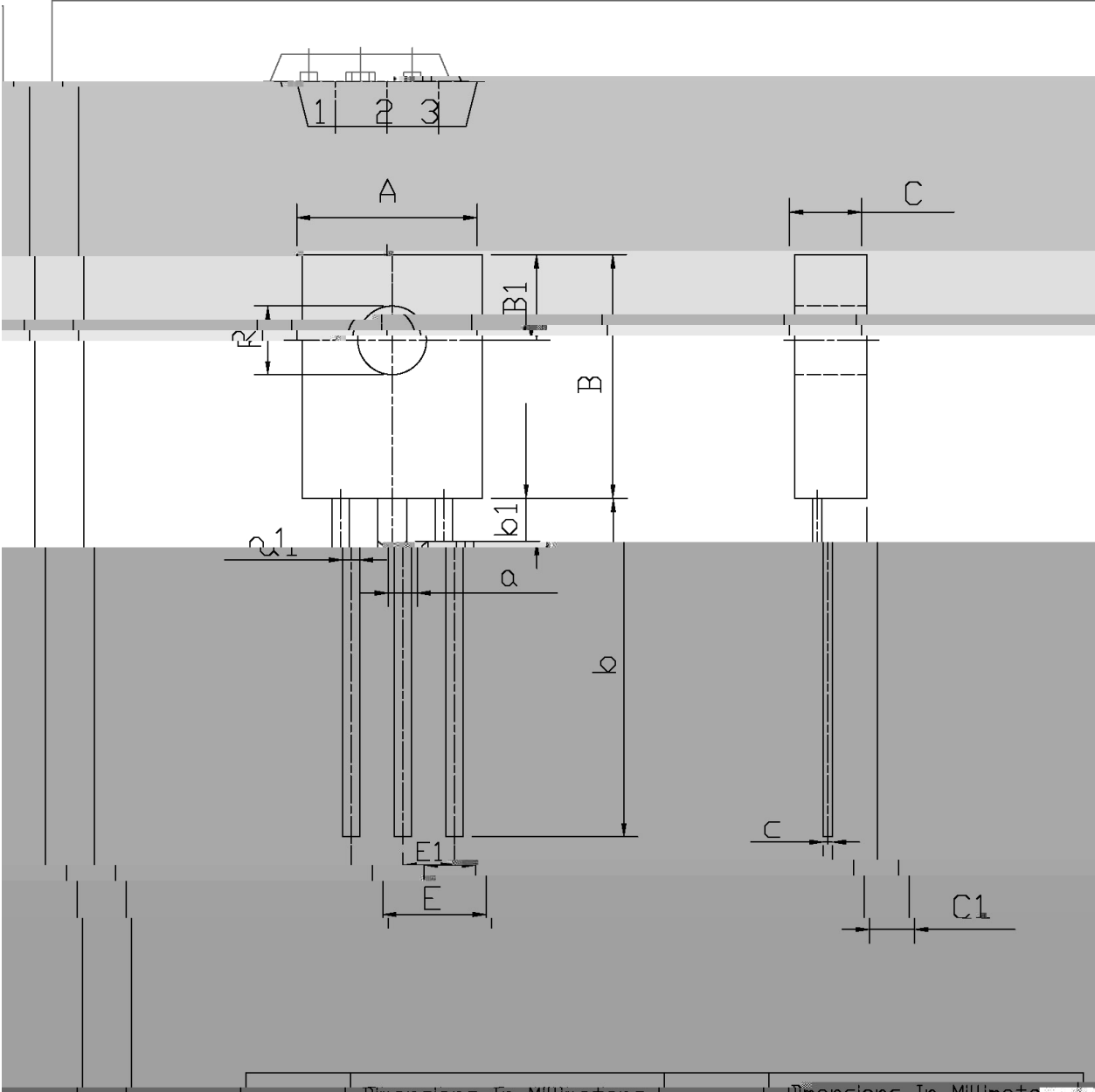
Electrical Characteristic Curve



/ Package Dimensions

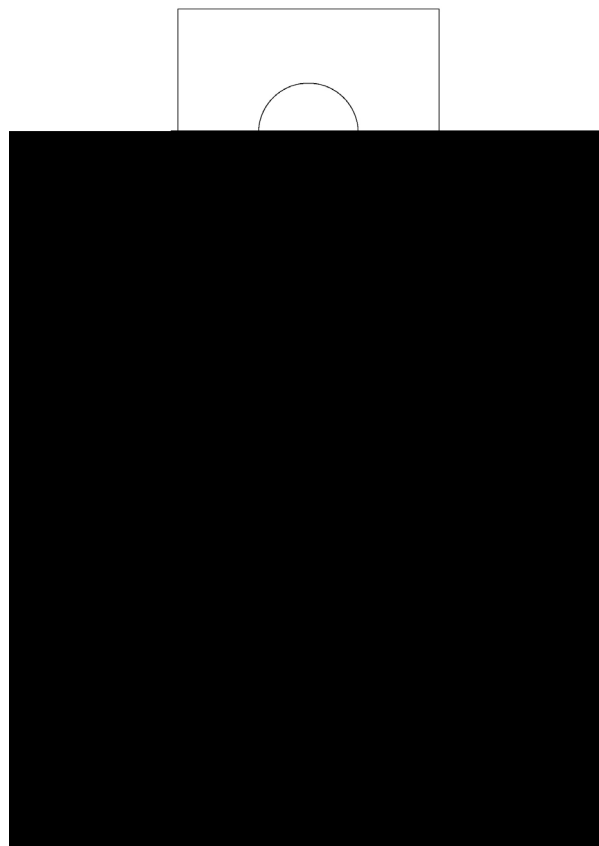
TU-126F

单位: mm



Symbol	Min	Max	Symbol	Min	Max
A	7.8	8.2	A1	0.65	0.85
B	10.9	11.3	B1	0.65	0.85
C	0.65	0.85	C1	0.65	0.85
E	0.65	0.85	E1	0.65	0.85

/ Marking Instructions



б " χ

EU χ

E97< χ

E=

---- χ

Note:

BR:

B649 :

B:

****:

№ 3 " Γб

№ 3 " Γб

№ k_{1H}' ° Γб

№ 1 f ḡ " Γб 1 & 1 f ḡ " ψ ρ

Company Code

Product Type.

h_{FE} Classifications Symbol

Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



б " X

- 1 Ё 25 Ё 150 † Ё 60 Ё 90sec;
- 2 Š 255 ° 5 † Ё 5 ° 0.5sec;
- 3 2 Ё 10 † /sec.

- Note:
- 1.Preheating:25~150 † , Time:60~90sec.
 - 2.Peak Temp.:255 ° 5 † , Duration:5 ° 0.5sec.
 - 3. Cooling Speed: 2~10 † /sec.

5	•	Ў 2	џ	B	I	255 °
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